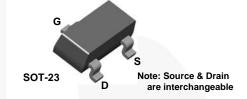


January 2015

MMBFJ309 / MMBFJ310 N-Channel RF Amplifier

Description

This device is designed for VHF/UHF amplifier, oscillator and mixer applications. As a common gate amplifier, 16 dB at 100 MHz and 12 dB at 450 MHz can be realized. Sourced from process 92. Source & Drain are interchangeable.



Ordering Information

Part Number	Top Mark	Package	Packing Method
MMBFJ309	6U	SOT-23 3L	Tape and Reel
MMBFJ310	6T	SOT-23 3L	Tape and Reel

Absolute Maximum Ratings(1), (2)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
V_{DG}	Drain-Gate Voltage	25	V
V_{GS}	Gate-Source Voltage	-25	V
I_{GF}	Forward Gate Current	10	mA
T_J , T_{STG}	Operating and Storage Junction Temperature Range	-55 to 150	°C

Notes:

- 1. These ratings are based on a maximum junction temperature of 150°C.
- These are steady-state limits. Fairchild Semiconductor should be consulted on applications involving pulsed or low-duty-cycle operations.

Thermal Characteristics(3)

Values are at T_A = 25°C unless otherwise noted.

Symbol	Parameter	Max.	Unit
D	Total Device Dissipation	350	mW
P_{D}	Derate Above 25°C	2.8	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	357	°C/W

Note:

3. Device mounted on FR-4 PCB 36mm × 18mm × 1.5mm; mounting pad for the collector lead minimum 6cm².

Electrical Characteristics

Values are at $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter Conditions		Min.	Тур.	Max.	Unit	
Off Chara	acteristics				I	I	
V _{(BR)GSS}	Gate-Source Breakdown Voltage	$I_G = -1.0 \mu\text{A}, V_{DS} = 0$		-25			V
I _{GSS}	Cata Bayaraa Currant	$V_{GS} = -15 \text{ V}, V_{DS} = 0$				-1.0	nA
	Gate Reverse Current	$V_{GS} = -15 \text{ V}, V_{DS} = 0, T_A$	= 125°C			-1.0	μΑ
	Cata Cauraa Cut O# Valtana	V 40 V L 40 pA	MMBFJ309	-1.0		-4.0	V
V _{GS(off)}	Gate-Source Cut-Off Voltage	$V_{DS} = 10 \text{ V}, I_{D} = 1.0 \text{ nA}$	MMBFJ310	-2.0		-6.5	٧
On Chara	ncteristics						
lago	Zero-Gate Voltage Drain Current ⁽⁴⁾	V _{DS} = 10 V, V _{GS} = 0	MMBFJ309	12		30	mA
I _{DSS}			MMBFJ310	24		60	IIIA
$V_{GS(f)}$	Gate-Source Forward Voltage	$V_{DS} = 0$, $I_{G} = 1.0 \text{ mA}$				1.0	V
Small Sig	nal Characteristics						
Re _(yis)	Common-Source Input Conductance	$V_{DS} = 10 \text{ V}, I_{D} = 10 \text{ mA},$	MMBFJ309		0.7		mmhos
		f = 100 MHz	MMBFJ310		0.5		
Re _(yos)	Common-Source Output Conductance	V _{DS} = 10 V, I _D = 10 mA, f = 100 MHz			0.25		mmhos
G _{pg}	Common-Gate Power Gain	V _{DS} = 10 V, I _D = 10 mA, f = 100 MHz			16		dB
Re _(yfs)	Common-Source Forward Transconductance	V _{DS} = 10 V, I _D = 10 mA, f = 100 MHz			12		mmhos
Re _(yig)	Common-Gate Input Conductance	V _{DS} = 10 V, I _D = 10 mA, f = 100 MHz			12		mmhos
_	Common-Source Forward	V _{DS} = 10 V, I _D = 10 mA,	MMBFJ309	10000		20000	
9 _{fs}	Transconductance	f = 1.0 kHz	MMBFJ310	8000		18000	μmhos
g _{oss}	Common-Source Output Conductance	$V_{DS} = 10 \text{ V}, I_{D} = 10 \text{ mA}, I_{D} = 10 \text{ mA}$	f = 1.0 kHz			150	μmhos
~	Common-Gate Forward Conductance	$V_{DS} = 10 \text{ V}, I_{D} = 10 \text{ mA},$	MMBFJ309		13000		μmhos
g_{fg}		f = 1.0 kHz	MMBFJ310		12000		
a	Common-Gate Output Conductance	V _{DS} = 10 V, I _D = 10 mA, MMBFJ309 f = 1.0 kHz MMBFJ310	MMBFJ309		100		umbos
g _{og}				150		μmhos	
C _{dg}	Drain-Gate Capacitance	$V_{DS} = 0$, $V_{GS} = -10 \text{ V}$, $f = 1.0 \text{ MHz}$			2.0	2.5	pF
C _{sg}	Source-Gate Capacitance	$V_{DS} = 0$, $V_{GS} = -10$ V, $f = 1.0$ MHz			4.1	5.0	pF
NF	Noise Figure	$V_{DS} = 10 \text{ V}, I_{D} = 10 \text{ mA}, f = 450 \text{ MHz}$			3.0		dB
e _n	Equivalent Short-Circuit Input Noise Voltage	V _{DS} = 10 V, I _D = 10 mA, f = 100 Hz			6.0		nV//Hz

Note:

4. Pulse test: pulse width $\leq 300~\mu s,~duty~cycle \leq 2.0\%$

Typical Performance Characteristics

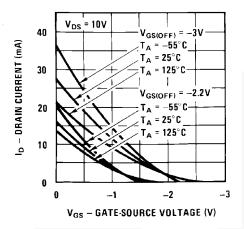


Figure 1. Transfer Characteristics

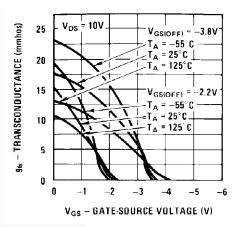


Figure 3. Transfer Characteristics

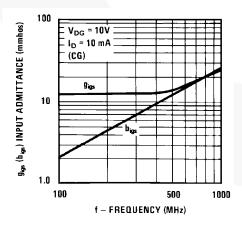


Figure 5. Input Admittance

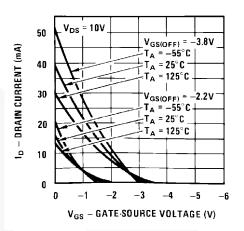


Figure 2. Transfer Characteristics

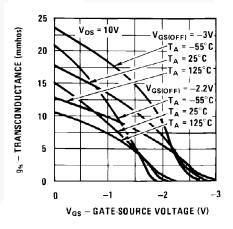


Figure 4. Transfer Characteristics

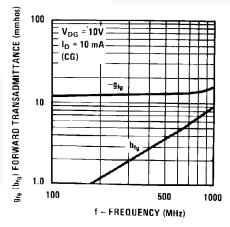


Figure 6. Forward Transadmittance

Typical Performance Characteristics (Continued)

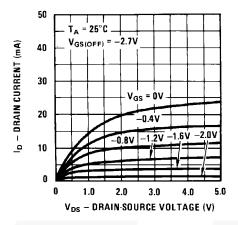
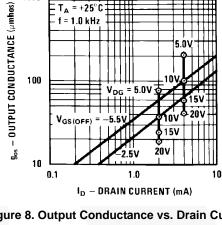


Figure 7. Common Drain-Source



1000

Figure 8. Output Conductance vs. Drain Current

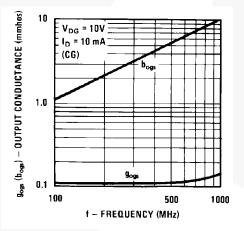


Figure 9. Output Admittance

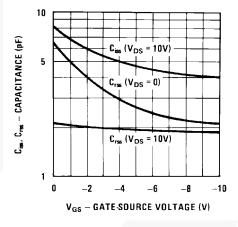


Figure 10. Capacitance vs. Voltage

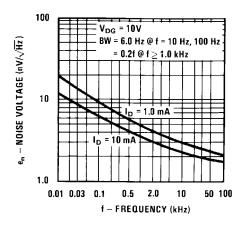


Figure 11. Noise Voltage vs. Frequency

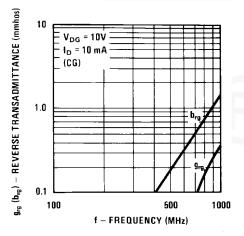


Figure 12. Reverse Transadmittance

Typical Performance Characteristics (Continued)

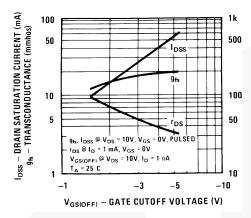


Figure 13. Parameter Interactions

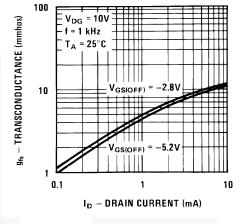


Figure 14. Transconductance vs. Drain Current

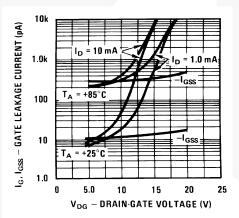


Figure 15. Leakage Current vs. Voltage

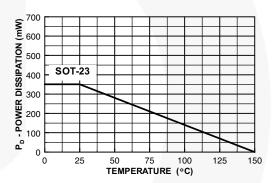
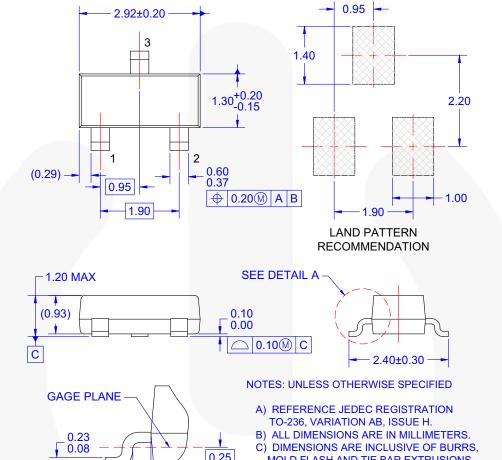


Figure 16. Power Dissipation vs. Ambient Temperature

Physical Dimensions



DETAIL A

(0.55)

0.20 MIN

Figure 17. 3-LEAD, SOT23, JEDEC TO-236, LOW PROFILE

0.25

PLANE

C) DIMENSIONS ARE INCLUSIVE OF BURRS,

ASME Y14.5M - 1994.

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